

Trans IGBT Chip N-CH 600V 60A 200mW 3-Pin(3+Tab) TO-247 Tube

Manufacturer: [STMicroelectronics, Inc](#)

Package/Case: TO-247

Product Type: Thyristors

Lifecycle: Active



Images are for reference only

[Inquiry](#)

General Description

This IGBT utilizes the advanced Power MESH process resulting in an excellent trade-off between switching performance and low on-state behavior.

Key Features

High frequency operation

Lower CRES/CIES ratio (no cross-conduction susceptibility)

Very soft ultra fast recovery anti-parallel diode

Low VCE (sat) for reduced conduction losses

Tight parameter distribution for design simplification and easy paralleling



Recommended For You

STGIF5CH60TS-L

STMicroelectronics, Inc
SDIP2B-26

STGIPS10K60A

STMicroelectronics, Inc
SDIP-25L

STP24NF10

STMicroelectronics, Inc
TO-220

STGW30NC120HD

STMicroelectronics, Inc
TO-247

STGIPS20K60

STMicroelectronics, Inc
SDIP-25

STB75NF75LT4

STMicroelectronics, Inc
TO-263

STD20NF06LT4

STMicroelectronics, Inc
TO-252

STGW45HF60WD

STMicroelectronics, Inc
TO-247

STGW19NC60HD

STMicroelectronics, Inc
TO-247

STGW40H120DF2

STMicroelectronics, Inc
TO-247

STGW40V60DF

STMicroelectronics, Inc
TO-247

STGB10NC60HD

STMicroelectronics, Inc
D2PAK

STGB30V60DF

STMicroelectronics, Inc
TO-263

STGP30H60DF

STMicroelectronics, Inc
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STGW40N120KD

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